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# LC709201F

CMOS IC

## Battery Monitor IC

### Overview

The LC709201F is an IC that measures the remaining power level of 1-cell lithium-ion secondary batteries by monitoring the battery voltage without an external sense resistor, and detects the remaining battery power level by current prediction. It monitors the battery voltage and realizes a function that precisely measures the remaining battery charge. In addition, the IC realizes the function for calculating the remaining battery power level even more accurately by utilizing a temperature correction function that makes use of the temperature input from a thermistor.

### Features

■Accuracy of remaining battery power level measurement

- Accuracy of  $\pm 5\%$  during discharging from 100% to 0% (at an ambient operating temperature of 0°C to 50°C)

■Measurement of remaining battery power level

- The remaining power level is measured four times a second and calculated with each measurement undertaken.

■Interface

- I<sup>2</sup>Cbus, communication in slave mode up to 100kHz supported

■Ports

- |  |              |
|--|--------------|
| • I <sup>2</sup> C-bus communication pin           | 2 (SDA, SCL) |
| • Battery temperature reading control pin          | 1 (TSW)      |
| • Analog voltage input pin for battery temperature | 1 (TSENSE)   |
| • Reset pin  | 1 (RESB)     |
| • TEST pin   | 1 (TEST)     |
| • Power supply pin                                 | 2 (VSS, VDD) |

■Package form

- MFP10S (225 mil): LC709201FM-01/02/03
- VCT16 (2.6×2.6): LC709201FRD-01/02/03

## Applications

- Cell phones, PDA devices, MP3 players, cordless phones, digital cameras, USB-related devices, etc.

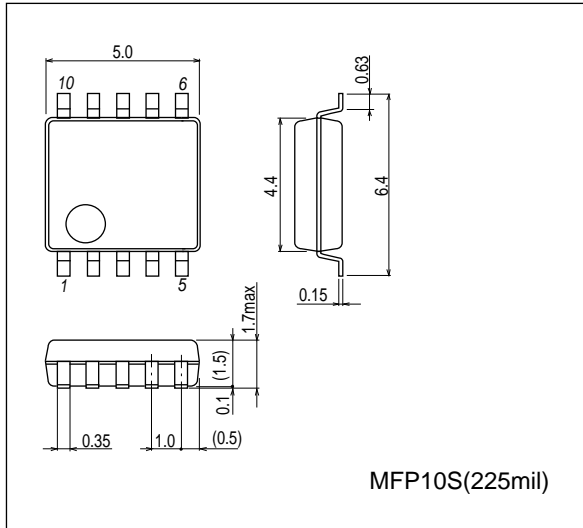
(Note) Depending on the kinds of battery, applicable model differs (LC709201F-01/02/03).

Please contact us for more detail information.

## Package Dimensions

unit : mm (typ)

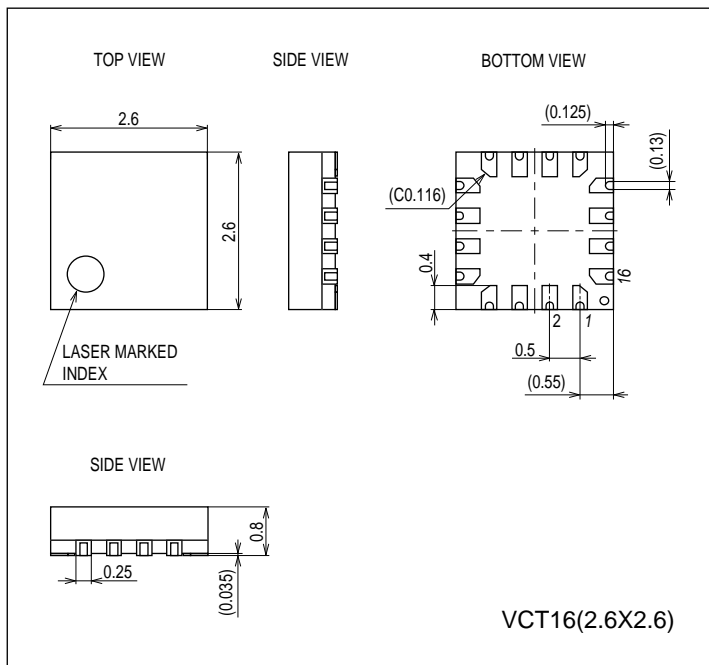
3086B



## Package Dimensions

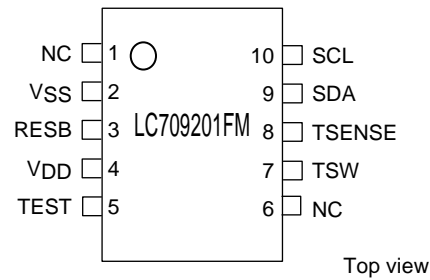
unit : mm (typ)

3318

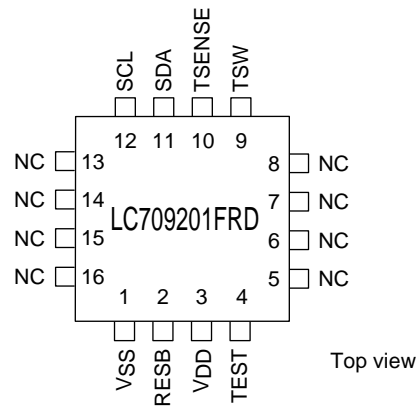


LC709201F

Pin Assignment

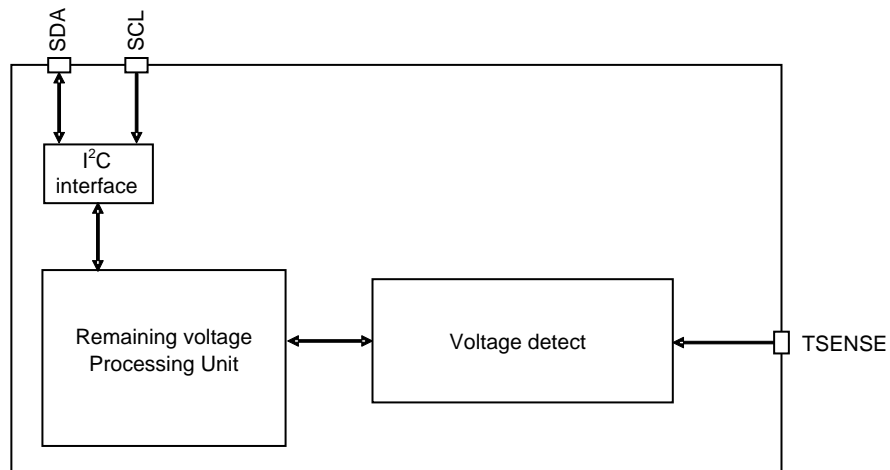


MFP10S (225mil) “Lead-free Type”



VCT16 (2.6×2.6) “Lead-free Type”

## Block Diagram



## Pin Function

Pin Name	I/O	Description
V <sub>SS</sub>	-	- power pin
V <sub>DD</sub>	-	+ power pin
RESB	I	Reset pin
TEST	I/O	Test pin *Connect an external 100kΩ pull-down resistor.
SDA	I/O	I <sup>2</sup> C data pin
SCL	I/O	I <sup>2</sup> C clock pin
TSW	O	Battery temperature reading control pin *Set high when reading in the temperature, held low at other times.
TSENSE	I	Battery temperature analog voltage input pin

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## Absolute Maximum Ratings at Ta=25°C, VSS=0V

Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	Specification			Unit
					min	typ	max	
Maximum supply voltage	V <sub>DD</sub> max	V <sub>DD</sub>			-0.3		+6.5	V
Input voltage	V <sub>I</sub> (1)	RESB, TSENSE			-0.3		V <sub>DD</sub> +0.3	
Output voltage	V <sub>O</sub> (1)	TSW			-0.3		V <sub>DD</sub> +0.3	
Input/output voltage	V <sub>IO</sub> (1)	SDA, SCL, TEST			-0.3		V <sub>DD</sub> +0.3	
Allowable power dissipation	Pd max	MFP10S	Ta=-40 to +85°C				110	mW
		VCT16					55	
Operating ambient temperature	Topr				-40		+85	°C
Storage ambient temperature	Tstg				-55		-125	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## Allowable Operating Conditions at Ta=-40 to +85°C, VSS=0V

Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	Specification			unit
					min	typ	max	
Operating supply voltage	V <sub>DD</sub> (1)	V <sub>DD</sub>			2.25		5.5	V
High level input voltage	V <sub>IH</sub> (1)	SDA, SCL		2.25 to 5.5	0.3V <sub>DD</sub> +0.7		V <sub>DD</sub>	
Low level input voltage	V <sub>IL</sub> (1)	SDA, SCL		4.0 to 5.5	V <sub>SS</sub>		0.1V <sub>DD</sub> +0.4	
	V <sub>IL</sub> (2)			2.25 to 4.0	V <sub>SS</sub>		0.2V <sub>DD</sub>	

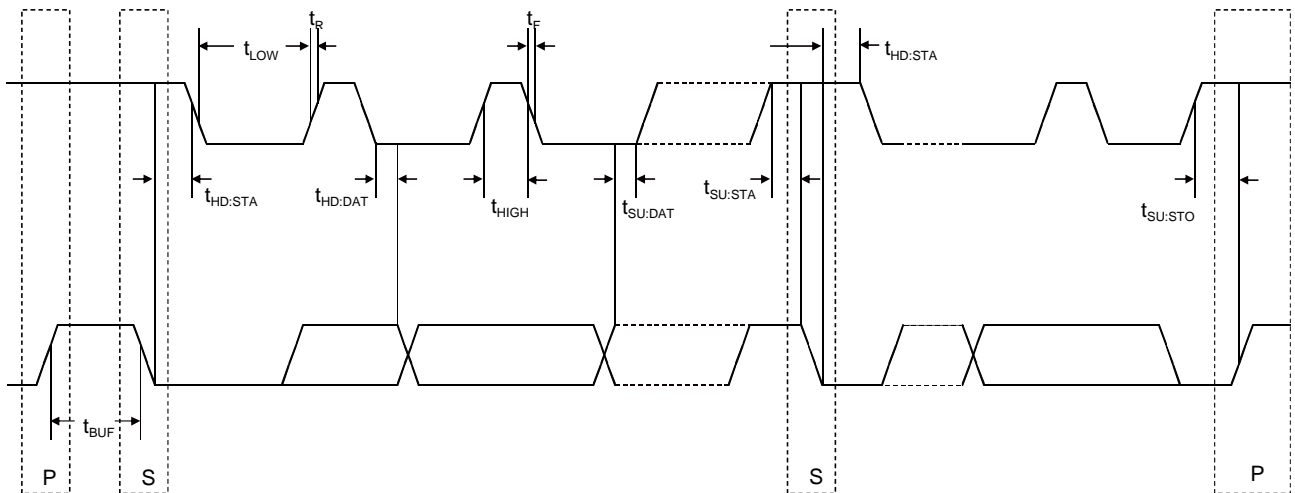
## Electrical Characteristics at Ta=-40 to +85°C, VSS=0V

Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	Specification			Unit
					min	typ	max	
High level input current	I <sub>IH</sub> (1)	RESB, SDA, SCL	V <sub>IN</sub> =V <sub>DD</sub> (including output transistor off leakage current)	2.25 to 5.5			1	μA
Low level input current	I <sub>IL</sub> (1)	RESB, SDA, SCL	V <sub>IN</sub> =V <sub>SS</sub> (including output transistor off leakage current)	2.25 to 5.5	-1			
High level output voltage	V <sub>OH</sub> (1)	TSW	I <sub>OH</sub> =-0.4mA	3.0 to 5.5	V <sub>DD</sub> -0.4			V
	V <sub>OH</sub> (2)		I <sub>OH</sub> =-0.2mA	2.25 to 5.5	V <sub>DD</sub> -0.4			
Low level output voltage	V <sub>OL</sub> (1)	TSW, SDA, SCL	I <sub>OL</sub> =3.0mA	3.0 to 5.5			0.4	
	V <sub>OL</sub> (2)		I <sub>OL</sub> =1.3mA	2.25 to 5.5			0.4	
Hysteresis voltage	VHYS	RESB, SDA, SCL		2.25 to 5.5		0.1V <sub>DD</sub>		
Pin capacitance	CP	All pins	Pins other than the pin under test V <sub>IN</sub> =V <sub>SS</sub> f=1 MHz Ta=25°C	2.25 to 5.5		10		pF
Consumption current	I <sub>DD</sub> (1)	V <sub>DD</sub>	When detecting remaining capacity	2.25 to 5.5		8	16	μA
	I <sub>DD</sub> (2)		When not detecting remaining capacity	2.25 to 5.5		5	12	

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## I<sup>2</sup>C Slave Characteristics at Ta=-40 to+85°C, V<sub>SS</sub>=0V

Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	Specification			unit
					min	typ	max	
Clock frequency	TSCL	SCL		2.25 to 5.5			100	kHz
Bus free time between STOP condition and START condition	TBUF	SCL, SDA	See Fig. 1.		4.7			μs
Hold time (repeated) START condition First clock pulse is generated after this interval	THD: STA	SCL, SDA	See Fig. 1.		4.0			μs
Repeated START condition setup time	TSU: STA	SCL, SDA	See Fig. 1.		4.7			μs
STOP condition setup time	TSU: STO	SCL, SDA	See Fig. 1.		4.0			μs
Data hold time	THD: DAT	SCL, SDA	See Fig. 1.		300			ns
Data setup time	TSU: DAT	SCL, SDA	See Fig. 1.		250			ns
Clock low period	TLOW	SCL			4.7			μs
Clock high period	THIGH	SCL			4.0			μs
Clock/data fall time	TF	SCL, SDA					300	ns
Clock/data rise time	TR	SCL, SDA					1000	ns



## Discharge Characteristics

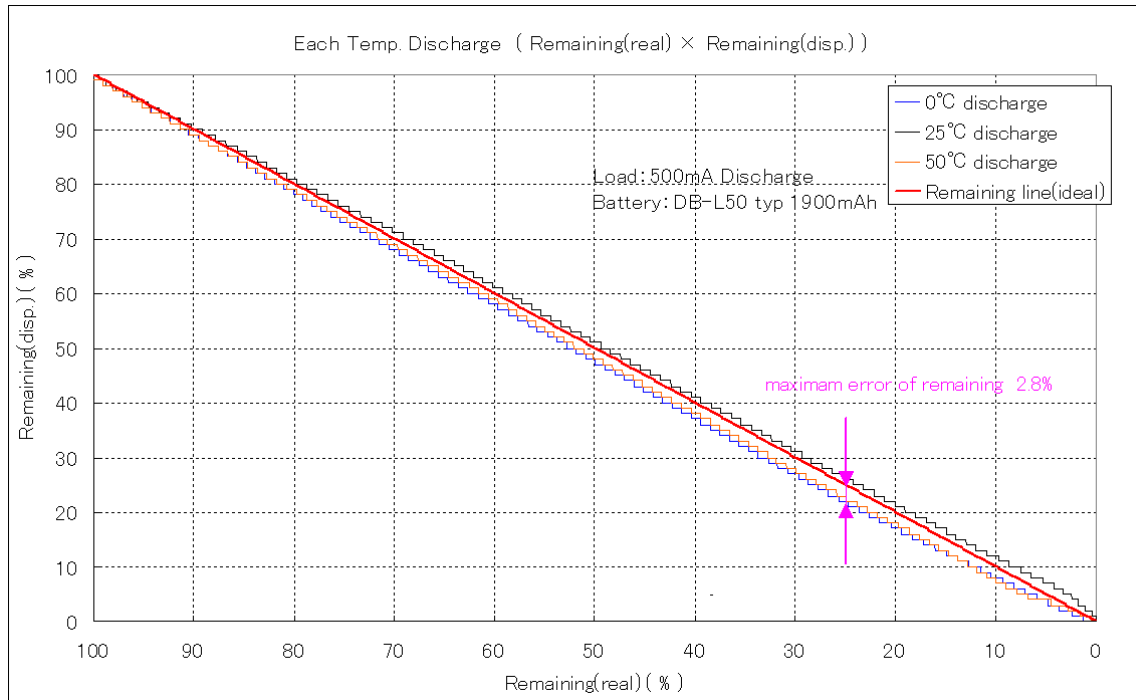


Figure2 Discharge Characteristics by Temperature Change

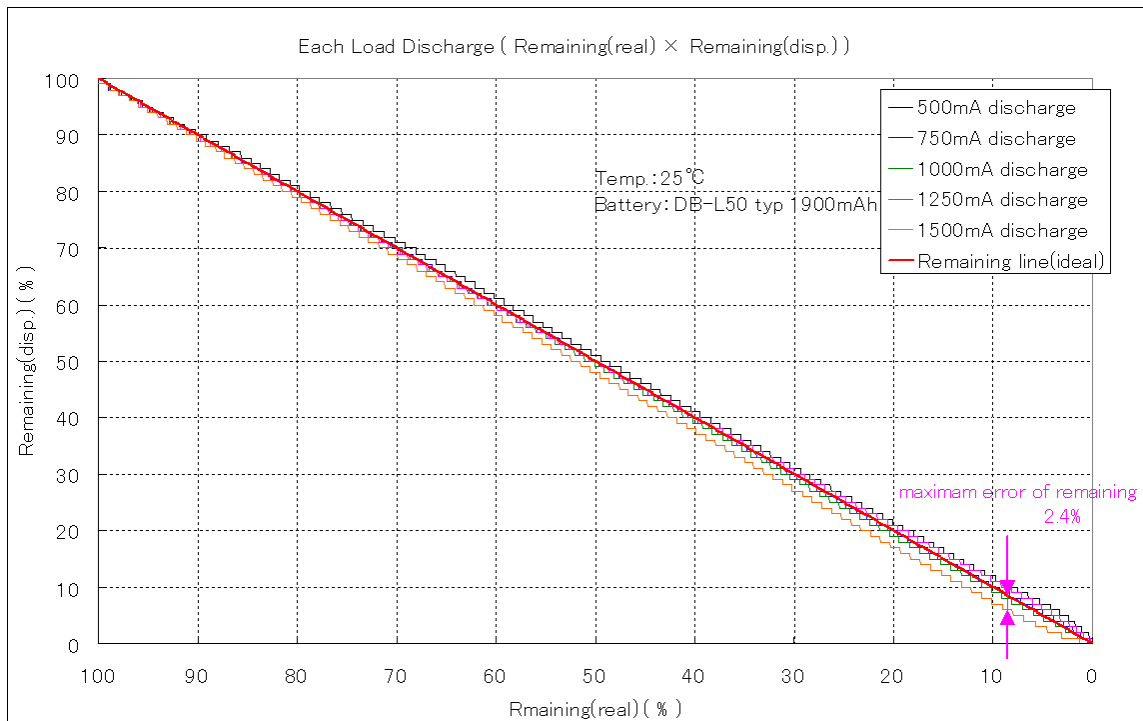


Figure 3 Discharge Characteristics by Load Change

## Communication Protocol

Communication protocol type: I<sup>2</sup>C



Frequency: 100kHz

Address: 0x16

### Bus Protocols

- S : Start Condition
- Sr : Repeated Start Condition
- Rd : Read (bit value of 1)
- Wr : Write (bit value of 0)
- A : ACK (bit value of 0)
- N : NACK (bit value of 1)
- P : Stop Condition

CRC-8 : Slave Address to Last Data (ex.3778mV: 0x16, 0x09, 0x17, 0xC2, 0x0E → 0x86)

-  : Master-to-Slave
-  : Slave-to-Master
- ... : Continuation of protocol

### Read Word Protocol

S	Slave Address	Wr	A	Command Code	A	...
Sr	Slave Address	Rd	A	Data Byte Low	A	Data Byte High ...
A	CRC-8	N	P			

### Write Word Protocol

S	Slave Address	Wr	A	Command Code	A	...
Data Byte Low	A	Data Byte High	A	CRC-8	A	P

Slave Functions	Command Code	Range	Access	Unit
Cell Temperature	0x08	0 to 65535	R	0.1°K
Cell Voltage	0x09	0 to 65535	R	mV
Current	0x0A	-32768 to 32767	R	mA
Adjustment Pack	0x0B	0 to 255	R	Value
Relative State Of Charge	0x0D	0 to 100	R	%
Remaining Capacity	0x0F	0 to 65535	R	mAh
Full Charge Capacity	0x10	0 to 65535	R	mAh
IC Version	0x11	0 to 65535	R	Version
Adjustment Thermistor	0x12	0 to 255	R	Value
Set Relative State Of Charge	0x08	0xA500 + 0 to 100	W	0xA500 + %
Adjustment Pack	0x08	0x5A00 + 0 to 255	W	0x5A00 + Value
Adjustment Thermistor	0x08	0xAA00 + 0 to 255	W	0xAA00 + Value
Initial Relative State Of Charge	0x09	0xAA55	W	-



## Application Circuit Example

Figure 4 Example of an application schematic using LC709201F

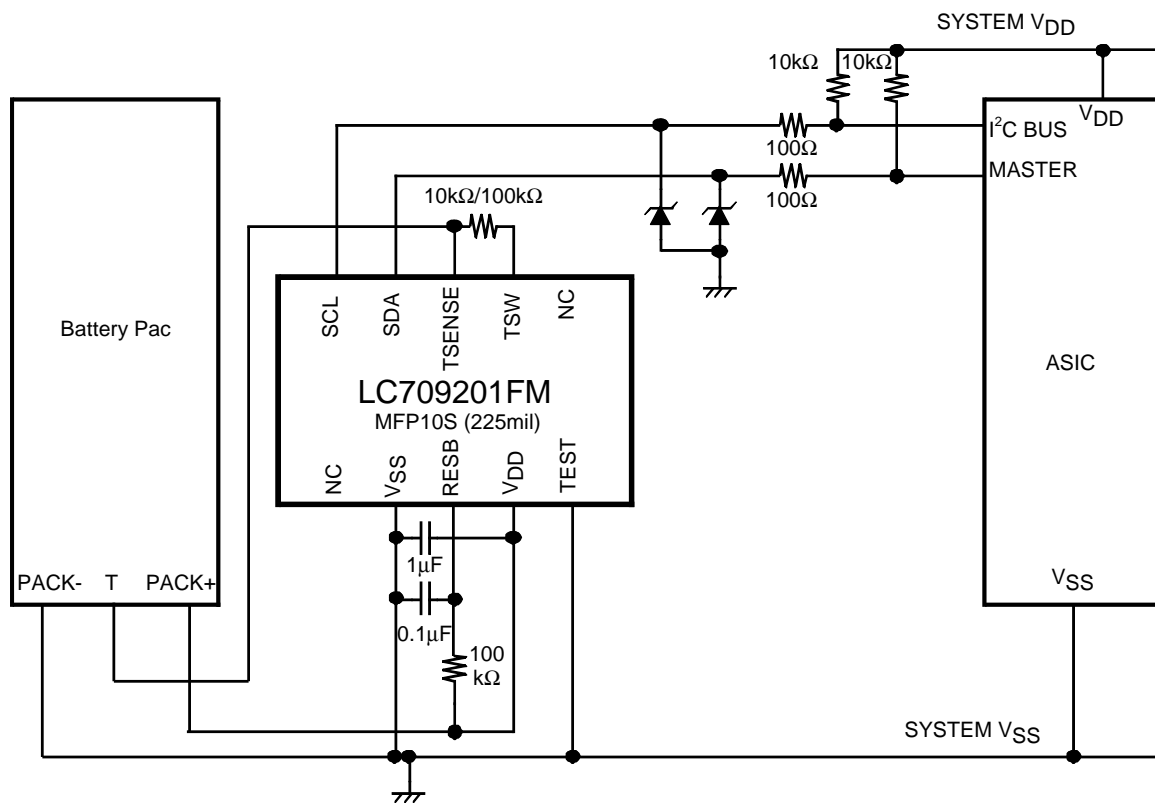
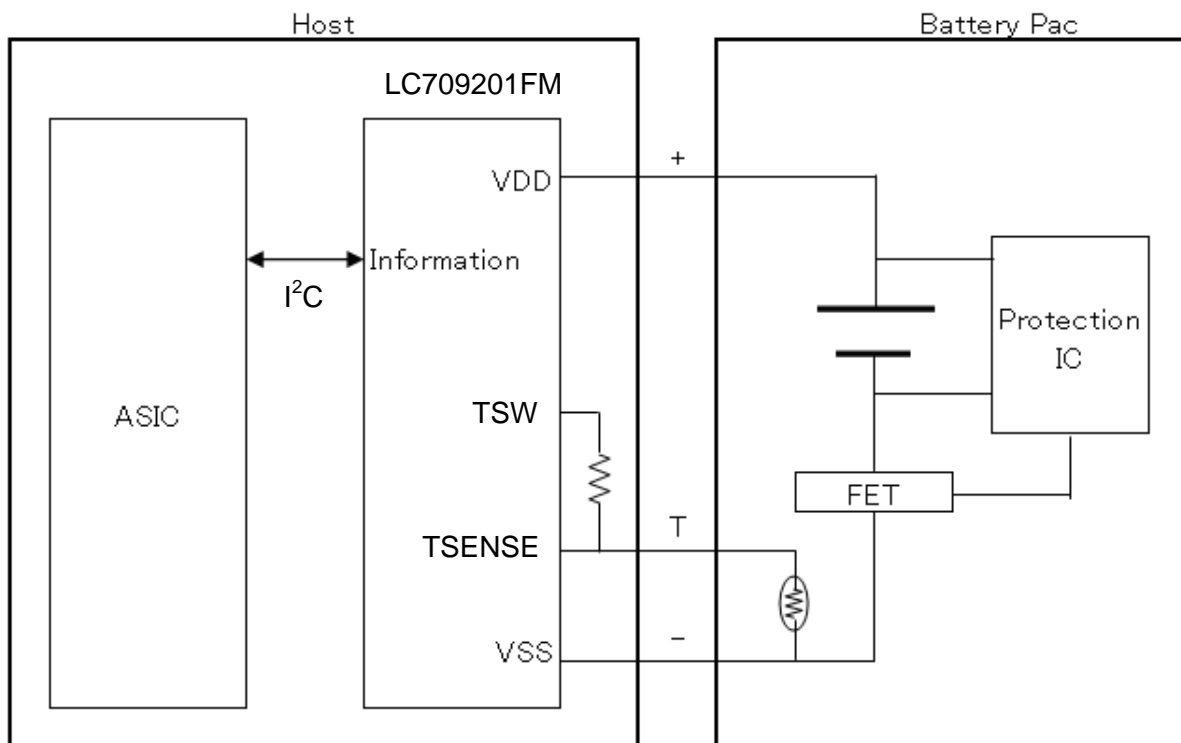


Figure 5 Conceptual diagram using LC709201F



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